

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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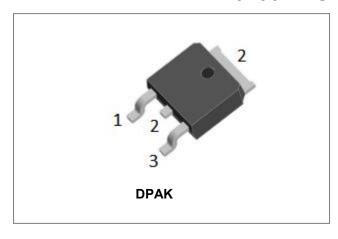


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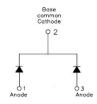
### MBRD20100CT SCHOTTKY RECTIFIER



#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =105°C, rectangular wave form	10(peg leg) 20(peg device)	Α
Peak One Cycle Non-Repetitive Surge Current(peg leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	120	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 10A, Pulse, T <sub>J</sub> = 25 °C	0.75	0.90	V
(per leg) *	V <sub>F2</sub>	@ 10A, Pulse, T <sub>J</sub> = 125 °C	0.64	0.84	V
Reverse Current (per leg) *	$I_{R1}$ @V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C		0.006	1.0	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	1	6.0	mA
Junction Capacitance(per leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C, f <sub>SIG</sub> = 1MHz	230	250	pF
Voltage Rate of Change	dv/dt	10,000		V/μs	

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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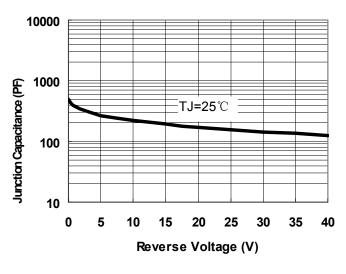




### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to + 150	°C
Typical Thermal Resistance Junction to Case(per leg)	$R_{ heta JC}$	-	3.5	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

### **Ratings and Characteristics Curves**



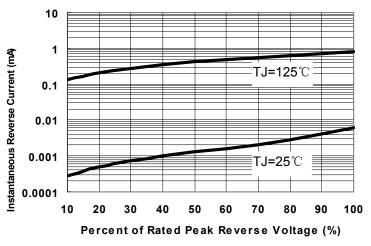


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

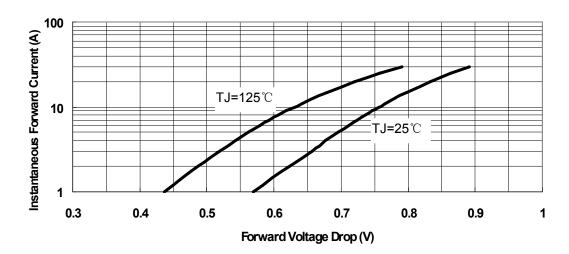


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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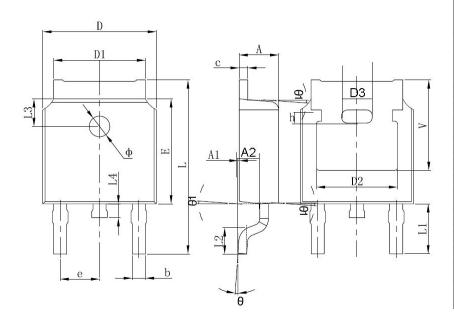


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### **Mechanical Dimensions DPAK**



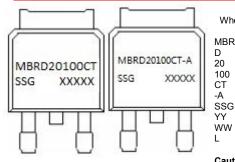
CVMPOL	Millimeters		Inches	
SYMBOL	Min.	Max.	Min.	Max.
Α	2.20	2.40	0.087	0.094
A1	0.00	0.127	0.000	0.005
b	0.66	0.86	0.026	0.034
С	0.46	0.60	0.018	0.024
D	6.50	6.70	0.256	0.264
D1	5.13	5.46	0.202	0.215
D2	4.83	REF.	0.190 REF.	
E	6.00	6.20	0.236	0.244
е	2.186	2.386	0.086	0.094
L	9.70	10.40	0.381	0.409
L1	2.90 REF.		0.144 REF.	
L2	1.40	1.70	0.055	0.067
L3	1.60 REF.		0.063 REF.	
L4	0.60	1.00	0.024	0.039
Ф	1.10	1.30	0.043	0.051
Θ	0°	8°	0°	8°
h	0.00	0.30	0.000	0.012
V	5.35 REF.		0.211 REF.	

### **Ordering Information**

Device	Package	Shipping
MBRD20100CT	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel Packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type
D = Package type
20 = Forward Current (20A)

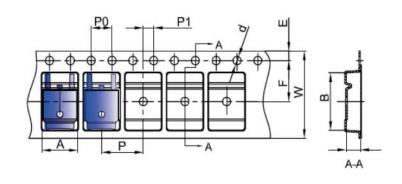
= Reverse Voltage (100V) = Configuration

= Configuration = AEC-Q101 = SSG = Year = Week

= Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

### **Carrier Tape Specification DPAK**



SYMBOL	Millimeters			
STIVIBUL	Min.	Max.		
Α	6.80	7.00		
В	10.40	10.60		
С	2.60	2.80		
d	Ф1.45	Ф1.65		
E	1.65	1.85		
F	7.40	7.60		
P0	3.90	4.10		
Р	7.90	8.10		
P1	1.90	2.10		
W	15.90	16.30		

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